

Integrated Omnipolar TMR Digital Latches

FEATURES AND BENEFITS

- Sensitivity with B_{OP} range: 9 to 70 G
- Ultra-low power consumption: ~110 nA @ V_{DD} = 1.8 V and f_S = 2 Hz
- Supply voltage range: 1.7 to 5.5 V
- Sensor polarity: omnipolar
- Digital CMOS outputs:
 Push-pull
 Open drain
- Undervoltage lockout (UVLO)
- Package options:
 □ 3-lead SOT23
 □ 4-lead LGA, 1.45 mm × 1.45 mm × 0.44 mm

APPLICATIONS

- IoT devices
- Smartphones, tablets, and laptops
- Door or lid closure
- Reed switch replacement
- Tamper-proofing for utility smart meters
- Fluid level sensing/detection
- Proximity detection
- Motor controllers
- Gimbals for camera systems in drones/UAVs
- Industrial machinery/robots
- Medical devices

DESCRIPTION

The CT813x series of omnipolar tunnel magnetoresistance (TMR) digital latches are designed for consumer and industrial applications. The devices are based on Allegro patented XtremeSenseTM TMR technology with integrated CMOS process to provide a monolithic solution for superior sensing performance. The CT813x digital latches offer stable magnetic operation over the operating temperature range.

This product family has very low power consumption—as low as 110 nA—which is ideal for battery-operated products where minimal current consumption is required. The devices support magnetic fields down to 9 G for applications where there is a large air gap requirement.

For applications that require a very small form factor and low profile, the CT813x is assembled in a 4-lead LGA package. They are also available in an industry-standard 3-lead SOT-23 package to support high-volume manufacturing for industrial markets.

PACKAGE:



3-lead SOT-23

Not to scale. 4-lead LGA package not shown.

FUNCTIONAL BLOCK DIAGRAMS

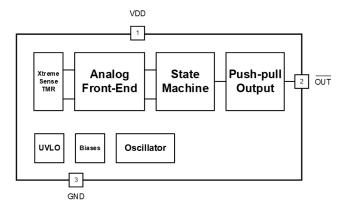


Figure 1: CT8132 with Push-Pull Output Block Diagram for 3-Lead SOT23 Package

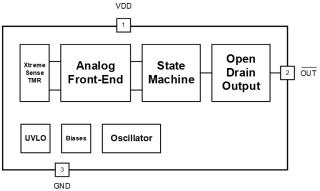


Figure 2: CT8131 with Open Drain Output Block Diagram for 3-Lead SOT23 Package

Integrated Omnipolar TMR Digital Latches

Table of Contents

1
1
1
1
2
4

Electrical Characteristics	5
Functional Description	
Applications Information	
XtremeSense TMR Current Sensor Location	
Package Outline Drawings	
Tape and Reel Pocket Drawings and Dimensions	
Package Information	
Revision History	

SELECTION GUIDE

Part Number	Operating Temp Range (°C)	Sensor Type	Output	B _{OP} (G)	B _{RP} (G)	f _S	Package	Packing
CT8131BV-IL4	-40 to 85	- Omnipolar		±30	±20	0.11	4-lead LGA	Tape and Reel
CT8131BV-HL4	-40 to 125		Open Drain	±30	±20	2 Hz	4-leau LGA	Tape and Reel
CT8131BV-IS3	-40 to 85	Omninglar	Onen Drain	±30	±20	2 Hz	2 load COT22	Tana and Daal
CT8131BV-HS3	-40 to 125	- Omnipolar	Open Drain	±30	±20	2 112	3-lead SOT23	Tape and Reel
CT8132BH-IL4	-40 to 85	Omninglar	Push-Pull	±30	±20	10 kHz	4-lead LGA	Tana and Daal
CT8132BH-HL4	-40 to 125	- Omnipolar	Pusn-Puli	±30	±20	TU KHZ	4-lead LGA	Tape and Reel
CT8132BH-IS3	-40 to 85	Omninglar	Push-Pull	±30	±20	10 10 1-	3-lead SOT23	Tana and Daal
CT8132BH-HS3	-40 to 125	Omnipolar	Pusn-Puli	±30	±20	10 kHz	3-lead 50123	Tape and Reel
CT8132BL-IS3	-40 to 85	Omninglar	polar Push-Pull	±30	120	250 11-	3-lead SOT23	Tana and Daal
CT8132BL-HS3	-40 to 125	- Omnipolar			±20	250 Hz		Tape and Reel
CT8132BV-IL4	-40 to 85	Omminalan	Push-Pull	±30	±20	2 Hz	4-lead LGA	Tana and Daal
CT8132BV-HL4	-40 to 125	- Omnipolar					4-lead LGA	Tape and Reel
CT8132BV-IS3	-40 to 85	Omminalan Duah Dull	±30	±20	2 Hz	3-lead SOT23	Tana and Daal	
CT8132BV-HS3	-40 to 125	- Omnipolar	ar Push-Pull	±30	±20	2 112	3-lead 50123	Tape and Reel
CT8132DM-IS3	-40 to 85	Omnipolar	Push-Pull	l ±15	±10	2.5 kHz	3-lead SOT23	Tape and Reel
CT8132DM-HS3	-40 to 125	Omnipolar	Pusn-Puli		±10			Tape and Reel
CT8132EK-IS3	-40 to 85	- Omnipolar	Push-Pull	±70	±50	10 Hz	3-lead SOT23	Tape and Reel
CT8132EK-HS3	-40 to 125		Pusn-Puli	±70	±50		3-lead 50123	Tape and Reel
CT8132SK-IL4	-40 to 85	Omminalan	Duck Dull	.0		40.11-		Tama and Daal
CT8132SK-HL4	-40 to 125	- Omnipolar	Push-Pull	±9	±5	10 Hz	4-lead LGA	Tape and Reel
CT8132SK-IS3	-40 to 85	Omninaler		10	15	10 11-	2 load COT22	Tana and Daal
CT8132SK-HS3	-40 to 125	- Omnipolar	Push-Pull	±9	±5	10 Hz	3-lead SOT23	Tape and Reel
CT8132SL-IS3	-40 to 85	Omninaler		10	15	250 11-	2 load COT22	Tana and Daal
CT8132SL-HS3	-40 to 125	Omnipolar	Push-Pull	±9	±5	250 Hz	3-lead SOT23	Tape and Reel



ABSOLUTE MAXIMUM RATINGS^[1]

Characteristic	Symbol	Notes		Rating	Unit
Supply Voltage	V _{DD}			-0.3 to 6.0	V
Push-Pull Output (Active Low)	V _{OUT_PP}			-0.3 to V _{DD} + 0.3 ^[2]	V
Open Drain Output (Active Low)	V _{OUT_OD}			-0.3 to 6.0	V
Analog Input/Output Pins Maximum Voltage	V _{I/O}			-0.3 to V _{DD} + 0.3 ^[2]	V
Input and Output Current	I _{IN} , I _{OUT}			±20.0	mA
Maximum Estamol Maximum dia Etabl		T _A = 25°C	CT8132Sx	±600	G
Maximum External Magnetic Field	B _{MAX}		CT813xBx, CT8132DM, CT8132EK	±2000	G
Electrostatic Discharge Dratestian Level	ESD	Human Body Model (HBM) per JESD22-A114		±4.0 (min)	kV
Electrostatic Discharge Protection Level	ESD	Charged Devi	ce Model (CDM) per JESD22-C101	±0.5 (min)	kV
Junction Temperature	TJ			-40 to 150	°C
Storage Temperature	T _{STG}			-65 to 155	°C
Lead Soldering Temperature	TL	10 seconds		260	°C

[1] Stresses exceeding the absolute maximum ratings may damage the CT813x and may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Allegro does not recommend exceeding or designing to absolute maximum ratings

 $^{[2]}$ The lower of V_DD + 0.3 V or 6.0 V.

RECOMMENDED OPERATING CONDITIONS^[1]

Characteristic	Symbol	Notes	Min.	Тур.	Max.	Unit
Supply Voltage Range	V _{DD}		1.7	3.3	5.5	V
Output Voltage Range	V _{OUT}		0	_	V _{DD}	V
Operating Magnetic Flux	B _{OP}	CT8132Sx	_	_	±450	G
Output Current	I _{OUT}		-	_	±3.0	mA
Bypass Capacitor	CBYP		-	1.0	-	μF
Operating Ambient Temperature	T _A	Industrial	-40	25	85	°C
		Extended Industrial	-40	25	125	°C

[1] The Recommended Operating Conditions table defines the conditions for actual operation of the CT813x. Recommended operating conditions are specified to ensure optimal performance to the specifications. Allegro does not recommend exceeding them or designing to absolute maximum ratings.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Value	Unit	
Junction-to-Ambient	R	Junction-to-ambient thermal resistance is a function of application and board layout and is determined in accordance to JEDEC standard JESD51 for a four (4) layer 2s2p FR-4 printed circuit board (PCB) with 2 oz. of copper (Cu) and	SOT23-3	202	°C/W
Thermal Resistance	1 OJA	4 oz. of copper (Cu) or more for 65 A. Special attention must be paid not to exceed junction temperature $T_{J(MAX)}$ at a given ambient temperature T_A .	LGA-4	165	°C/W



PINOUT DIAGRAMS AND TERMINAL LISTS

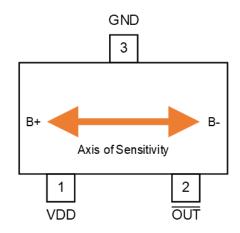


Figure 3: CT813x 3-Lead SOT23 Package for Digital Output (Top-Down View)

Terminal List

Number	Name	Function						
1	VDD	Supply Voltage						
2	OUT	Output Signal (Active Low)						
3	GND	Ground						

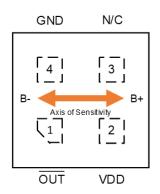


Figure 4: CT8131 4-Lead LGA Package with Digital Output (Top View)

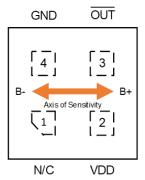


Figure 5: CT8132 4-Lead LGA Package with Digital Output (Top View)

Terminal List

Number	CT8131	CT8132	Function
1	OUT	NC	Output Signal for Open Drain (Active Low); N/C – No Connect
2	VDD	VDD	Supply Voltage
3	NC	OUT	Output Signal for Push-Pull (Active Low); N/C – No Connect
4	GND	GND	Ground



ELECTRICAL CHARACTERISTICS: Valid for V_{DD} = 1.7 to 5.5 V, C_{BYP} = 1.0 μ F, and T_A = -40°C to 125°C, typical values are V_{DD} = 3.3 V and T_A = 25°C, unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
PUSH-PULL OUTPUT						
Output Voltage High OUT ^[1]	V _{OH}	I _{OUT} = -2 mA	$0.9 \times V_{DD}$	_	-	V
Output Voltage Low OUT [1]	V _{OL}	I _{OUT} = 2 mA	-	_	0.1 × V _{DD}	V
OPEN DRAIN OUTPUT						
Output Voltage High ^[1]	V _{OH}		-	_	5.5	V
Output Voltage Low	V _{OL}	I _{OUT} ≤ 20 mA	0	-	0.5	V
High Output Leakage Current ^[1]	I _{LEAK}	V _{OH} = 5.5 V, B _{OP} = 0	-	20	-	pА
TIMINGS						
Power-On Time ^[1]	t _{ON}	V _{DD} ≥ 1.7 V	-	50	75	μs
Active Mode Time ^[1]	t _{ACTIVE}		-	2.6	-	μs
PROTECTION						
Lindom voltage Leokout [1]	N	Rising V _{DD}	-	1.60	1.64	V
Undervoltage Lockout ^[1]	V _{UVLO}	Falling V _{DD}	1.44	1.53	-	V
UVLO Hysteresis [1]	V _{UV_HYS}		-	70	-	mV

^[1] Guaranteed by design and characterization; not tested in production.

TYPICAL TIMING CHARACTERISTICS

 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 μF (unless otherwise specified)

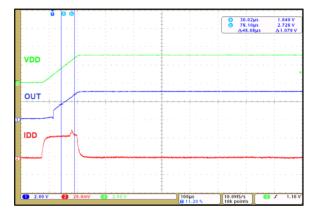
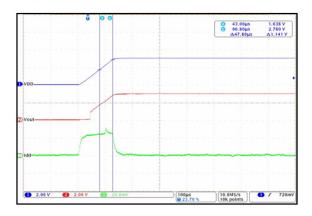


Figure 6: Power-On Time for Push-Pull Output







CT8131BV - ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for

$V_{PP} = 1.7 \text{ to } 5.5 \text{ V} \text{ C}_{0}$	$_{\rm NYP}$ = 1.0 µF, and $T_{\rm A}$ = -40°C to 12	25°C typical values are V	$r_{PD} = 3.3 \text{ V}$ and $T_{A} = 25^{\circ}\text{C}$

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	140	900	nA
	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	110	900	nA
Sampling Frequency	f _{S1}		1	2	4	Hz
Idle Mode Time	t _{IDLE1}	f _S = 2 Hz	250	500	1000	ms
Operate Point, B+	B _{OPS}		23	30	38	G
Operate Point, B–	B _{OPN}		-38	-30	-23	G
Release Point, B+	B _{RPS}		14	20	27	G
Release Point, B–	B _{RPN}		-27	-20	-14	G
Hysteresis	B _{HYST}		5	10	_	G

CT8132BH – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for V_{DD} = 1.7 to 5.5 V, C_{BYP} = 1.0 µF, and T_A = -40°C to 125°C, typical values are V_{DD} = 3.3 V and T_A = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	45	57	μA
	I _{DD(AVG)_1.8V}	t \ge 10 seconds, V _{DD} = 1.8 V	-	41	47	μA
Sampling Frequency	f _S		6	10	14	kHz
Idle Mode Time	t _{IDLE}	f _S = 10 kHz	71	100	167	μs
Operate Point, B+	B _{OPS}		23	30	38	G
Operate Point, B–	B _{OPN}		-38	-30	-23	G
Release Point, B+	B _{RPS}		14	20	27	G
Release Point, B–	B _{RPN}		-27	-20	-14	G
Hysteresis	B _{HYST}		5	10	-	G



CT8132BL - ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for

	10° C to 10° C typically	values are V_{DD} = 3.3 V and T_A = 25°C
$V_{DD} = 1 / 10 2 2$	-40 C 10 125 C IVOICAL	

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	1.3	3.0	μA
Average Supply Current	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	1.1	2.0	μA
Sampling Frequency	f _S		150	250	350	Hz
Idle Mode Time	t _{IDLE}	f _S = 250 Hz	2.8	4.0	6.7	ms
Operate Point, B+	B _{OPS}		23	30	38	G
Operate Point, B–	B _{OPN}		-38	-30	-23	G
Release Point, B+	B _{RPS}		14	20	27	G
Release Point, B-	B _{RPN}		-27	-20	-14	G
Hysteresis	B _{HYST}		5	10	-	G

CT8132BV – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for V_{DD} = 1.7 to 5.5 V, C_{BYP} = 1.0 µF, and T_A = -40°C to 125°C, typical values are V_{DD} = 3.3 V and T_A = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	140	900	nA
Average Supply Current	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	110	700	nA
Sampling Frequency	f _S		1	2	4	Hz
Idle Mode Time	t _{IDLE}	f _S = 2 Hz	250	500	1000	ms
Operate Point, B+	B _{OPS}		23	30	38	G
Operate Point, B–	B _{OPN}		-38	-30	-23	G
Release Point, B+	B _{RPS}		14	20	27	G
Release Point, B–	B _{RPN}		-27	-20	-14	G
Hysteresis	B _{HYST}		5	10	_	G



4.00

3.00

2.00

1.00

0.00

-1.00 -2.00

-3.00

-50

- BOP

BOP

-20

10

Figure 10: B_{OP} (Orange) and B_{OP} (Green) vs.

Temperature at V_{DD} = 3.3 V

40

Operating Temperature (°C)

70

100

130

(mT)

B_{OP}

TYPICAL MAGNETIC CHARACTERISTICS FOR CT813xBV, CT8132BH AND CT8132BL

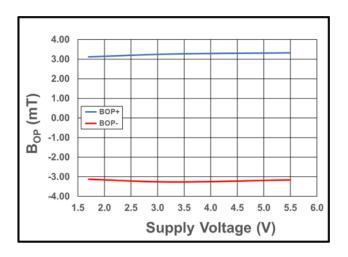


Figure 8: B_{OP-} (Red) and B_{OP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

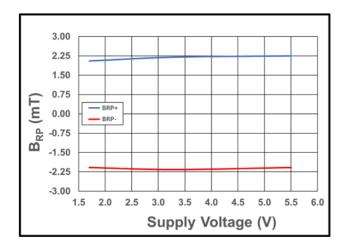


Figure 9: B_{RP-} (Red) and B_{RP+} (Blue) vs. Supply Voltage at T_A = 25°C

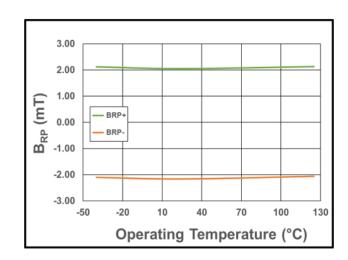
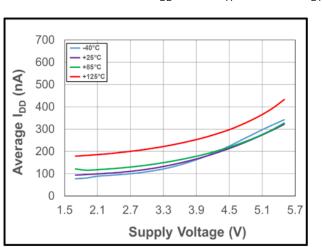


Figure 11: B_{RP-} (Orange) and B_{RP+} (Green) vs. Temperature at V_{DD} = 3.3 V





vs. Temperature

TYPICAL ELECTRICAL CHARACTERISTICS FOR CT813xBV

700

600

500

400

300

200

100

0

-50

-20

Average I_{DD} (nA)

 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 µF (unless otherwise specified)



10

40

70

Temperature (°C)

100

VDD = 1.8 V

VDD = 2.7 V

VDD = 3.0 V

- VDD = 3.3 V

- VDD = 3.6 V VDD = 5.0 V

130

160

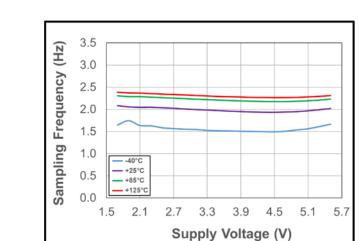
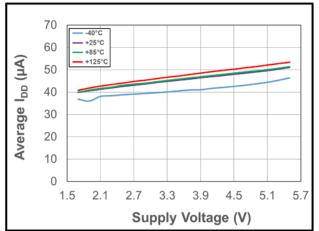


Figure 14: Sampling Frequency vs. Supply Voltage vs. Temperature









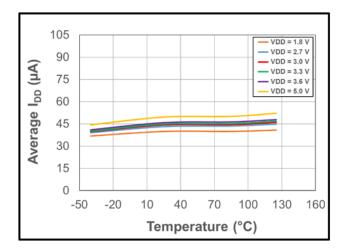


Figure 16: Average Supply Current vs. Temperature vs. Supply Voltage

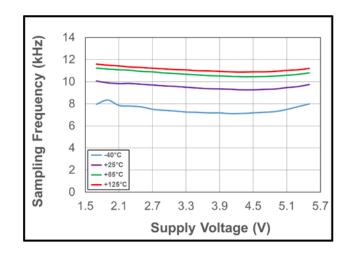
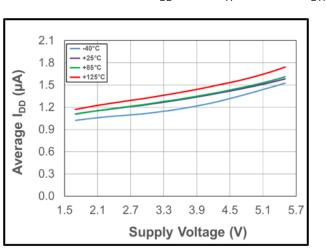


Figure 17: Sampling Frequency vs. Supply Voltage vs. Temperature





TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132BL

 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 µF (unless otherwise specified)

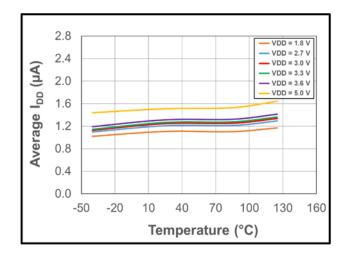


Figure 18: Average Supply Current vs. Supply Voltage vs. Temperature

Figure 19: Average Supply Current vs. Temperature vs. Supply Voltage

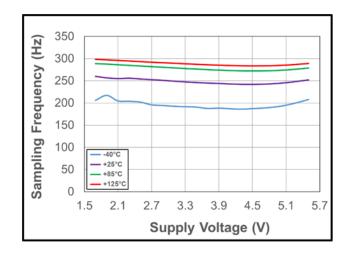


Figure 20: Sampling Frequency vs. Supply Voltage vs. Temperature



Integrated Omnipolar TMR Digital Latches

CT8132DM - ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for

$V_{PP} = 1.7 \text{ to } 5.5 \text{ V}$	$C_{\rm EVE} = 1.0 \mu \text{E}$ and $T_{\rm e}$	$= -40^{\circ}$ C to 125°C	typical values are V _P	$_{\rm D}$ = 3.3 V and T _A = 25°C
	$, \mathbf{O}_{B}VP = 1.0 \ \mu \mathrm{I}, a \mathrm{I}\mathrm{U} \mathrm{I}_{L}$	$1 = -\frac{1}{4}0 0 10 120 0$		$n = 0.0$ v and $1\Delta = 200$

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	11.5	15.0	μA
Average Supply Current	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	10.5	12.0	μA
Sampling Frequency	f _S		1.5	2.5	3.5	kHz
Idle Mode Time	t _{IDLE}	f _S = 2.5 kHz	285	400	667	μs
Operate Point, B+	B _{OPS}		11	15	19	G
Operate Point, B–	B _{OPN}		-19	-15	-11	G
Release Point, B+	B _{RPS}		6	10	14	G
Release Point, B–	B _{RPN}		-14	-10	-6	G
Hysteresis	B _{HYST}		3	5	_	G





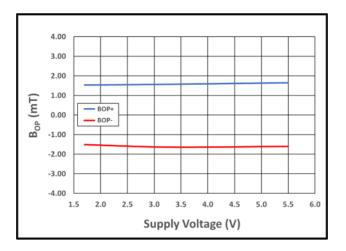


Figure 21: B_{OP-} (Red) and B_{OP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

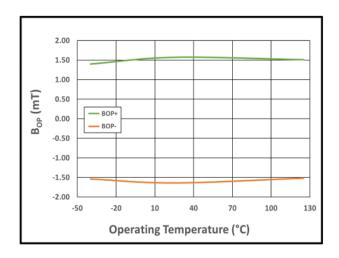


Figure 23: B_{OP-} (Orange) and B_{OP+} (Green) vs. Temperature at V_{DD} = 3.3 V

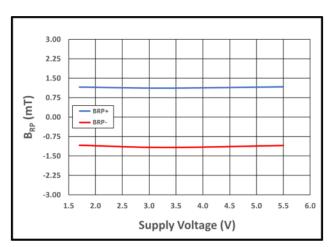


Figure 22: B_{RP-} (Red) and B_{RP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

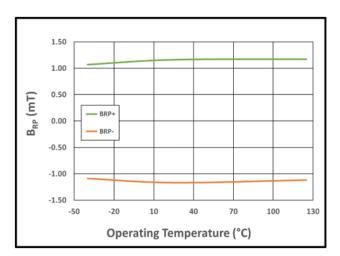
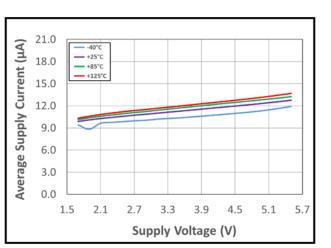


Figure 24: B_{RP-} (Orange) and B_{RP+} (Green) vs. Temperature at V_{DD} = 3.3 V





TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132DM

28.0

24.0

20.0

16.0

12.0

8.0

4.0

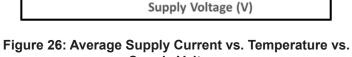
0.0

-50

-20

Average Supply Current (μA)

 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 µF (unless otherwise specified)



40

70

100

10

VDD = 1.8 V

VDD = 2.7 V

VDD = 3.0 V

VDD = 3.3 V

-VDD = 3.6 V -VDD = 5.0 V

130

160



Supply Voltage

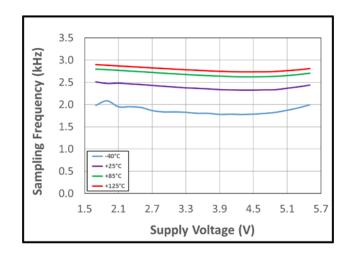


Figure 27: Sampling Frequency vs. Supply Voltage vs. Temperature



Integrated Omnipolar TMR Digital Latches

CT8132EK - ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for

V_{DD} = 1.7 to 5.5 V, C_{BYP} = 1.0 μ F,	, and T _A = –40°C to 125°C	C, typical values are V _{DD} = 3.3	V and $T_A = 2$	25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	-	190	900	nA
	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	145	700	nA
Sampling Frequency	f _S		6	10	14	Hz
Idle Mode Time	t _{IDLE}	f _S = 10 Hz	71	100	166	ms
Operate Point, B+	B _{OPS}		62	70	78	G
Operate Point, B–	B _{OPN}		-78	-70	-62	G
Release Point, B+	B _{RPS}		42	50	60	G
Release Point, B–	B _{RPN}		-60	-50	-42	G
Hysteresis	B _{HYST}		12	20	—	G



9.00

6.00

3.00

0.00

-3.00

-6.00

-9.00

-50

BOP

BOP

-20

10

40

Operating Temperature (°C)

Figure 30: B_{OP-} (Orange) and B_{OP+} (Green) vs. Temperature at V_{DD} = 3.3 V

70

100

130

B_{OP} (mT)



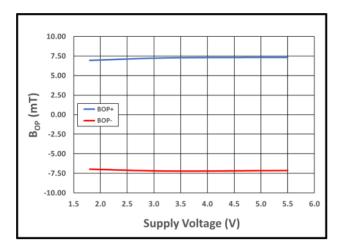


Figure 28: B_{OP-} (Red) and B_{OP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

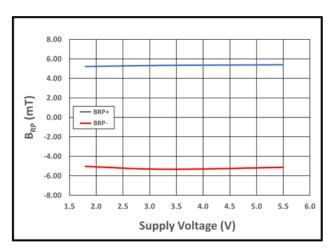


Figure 29: B_{RP-} (Red) and B_{RP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

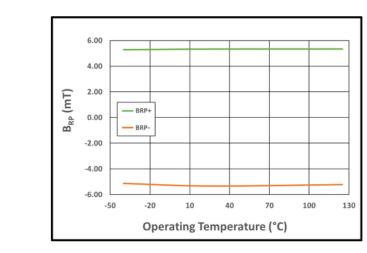
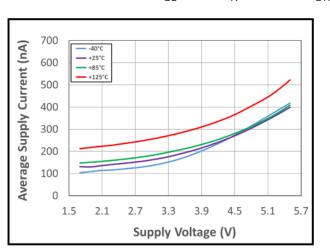


Figure 31: B_{RP-} (Orange) and B_{RP+} (Green) vs. Temperature at V_{DD} = 3.3 V





TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132EK



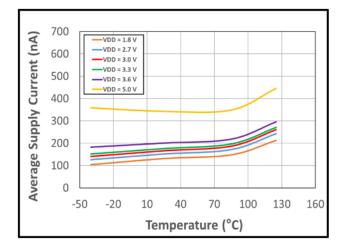


Figure 33: Average Supply Current vs. Temperature vs. Supply Voltage

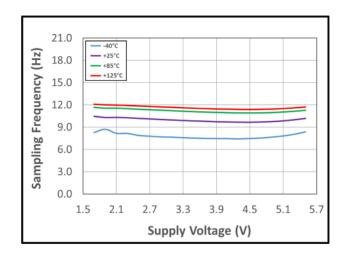


Figure 34: Sampling Frequency vs. Supply Voltage vs. Temperature



CT8132SK - ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for

$V_{PP} = 1.7 \text{ to } 5.5 \text{ V} \text{ C}$	$C_{BYP} = 1.0 \ \mu F$, and $T_A =$	-40°C to 125°C typ	ical values are Vpp =	3.3 V and $T_{1} = 25^{\circ}\text{C}$
$v_{1} = 1.7 \ 0.0 \ v_{2}$	$\mu_{\rm RYP} = 1.0 \ \mu {\rm I}$, and $1_{\rm A} =$			

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t ≥ 10 seconds	_	190	900	nA
Average Supply Current	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	145	700	nA
Sampling Frequency	f _S		6	10	14	Hz
Idle Mode Time	t _{IDLE}	f _S = 10 Hz	71	100	166	ms
Operate Point, B+	B _{OPS}		7	9	12	G
Operate Point, B–	B _{OPN}		-12	-9	-7	G
Release Point, B+	B _{RPS}		3	5	7	G
Release Point, B–	B _{RPN}		-7	-5	-3	G
Hysteresis	B _{HYST}		3	4	_	G

CT8132SL – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for V_{DD} = 1.7 to 5.5 V, C_{BYP} = 1.0 µF, and T_A = -40°C to 125°C, typical values are V_{DD} = 3.3 V and T_A = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I _{DD(AVG)}	t≥10 seconds	-	1.3	3.0	μA
Average Supply Current	I _{DD(AVG)_1.8V}	$t \ge 10$ seconds, $V_{DD} = 1.8$ V	-	1.1	2.0	μA
Sampling Frequency	f _S		150	250	350	Hz
Idle Mode Time	t _{IDLE}	f _S = 250 Hz	2.8	4.0	6.7	ms
Operate Point, B+	B _{OPS}		7	9	12	G
Operate Point, B–	B _{OPN}		-12	-9	-7	G
Release Point, B+	B _{RPS}		3	5	7	G
Release Point, B–	B _{RPN}		-7	-5	-3	G
Hysteresis	B _{HYST}		3	4	_	G





 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 µF (unless otherwise specified)

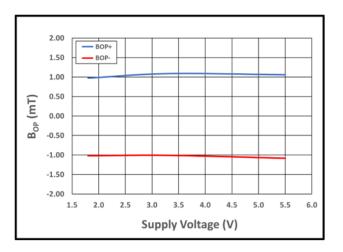


Figure 35: B_{OP-} (Red) and B_{OP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

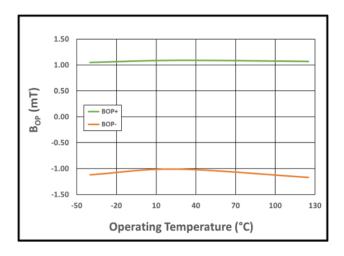


Figure 37: B_{OP-} (Orange) and B_{OP+} (Green) vs. Temperature at V_{DD} = 3.3 V

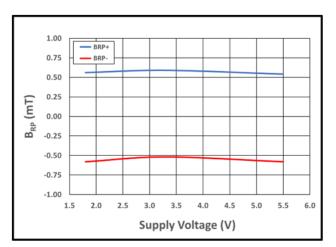


Figure 36: B_{RP-} (Red) and B_{RP+} (Blue) vs. Supply Voltage at $T_A = 25^{\circ}C$

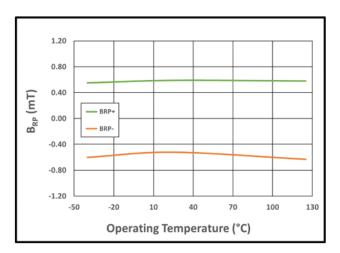
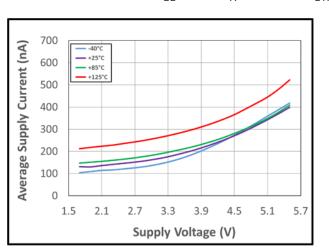
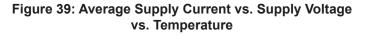


Figure 38: B_{RP-} (Orange) and B_{RP+} (Green) vs. Temperature at V_{DD} = 3.3 V





TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132SK



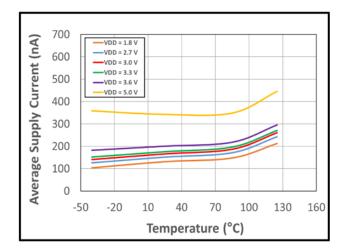


Figure 40: Average Supply Current vs. Temperature vs. Supply Voltage

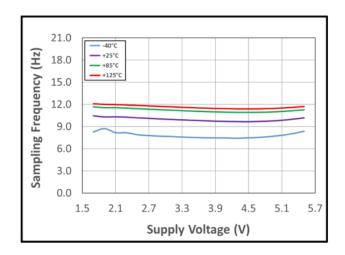
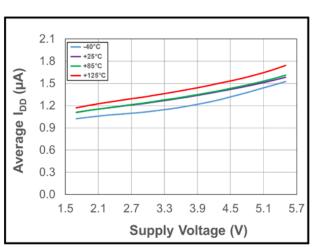


Figure 41: Sampling Frequency vs. Supply Voltage vs. Temperature





TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132SL

 V_{DD} = 3.3 V, T_A = 25°C, and C_{BYP} = 1.0 µF (unless otherwise specified)

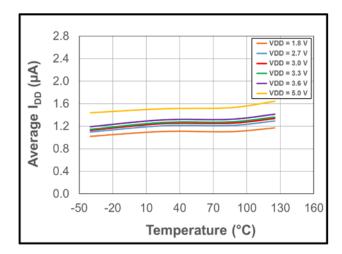


Figure 42: Average Supply Current vs. Supply Voltage vs. Temperature

Figure 43: Average Supply Current vs. Temperature vs. Supply Voltage

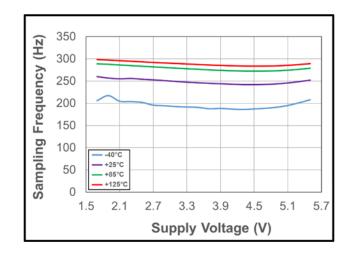


Figure 44: Sampling Frequency vs. Supply Voltage vs. Temperature



FUNCTIONAL DESCRIPTION

Overview

The CT813x is a product family of omnipolar TMR magnetic latches that supports a wide operating voltage range of 1.7 to 5.5 V and is capable of providing two digital output configurations: open drain or push-pull. These omnipolar TMR digital latches are designed to consume a minimal amount of current which is ideal for battery-operated products. It also supports a wide range of sensitivity levels for various applications.

Undervoltage Lockout (UVLO)

The Undervoltage Lockout protection circuitry of the CT813x is activated when the supply voltage (V_{DD}) falls below 1.53 V. The CT813x remains in a low quiescent state and the \overline{OUT} output is not valid until V_{DD} rises above the UVLO threshold (1.60 V).

Power-On Time (t_{ON})

The Power-On Time (t_{ON}) of 50 µs is the amount of time required by the CT813x to start up, power-on, and acquire the first sample. The chip is fully powered up and operational from the moment the supply voltage passes the rising UVLO point (1.60 V). This time includes the ramp-up time and the settling time (within 10% of steady-state voltage under an applied magnetic field) after the power supply have reach the minimum V_{DD} .

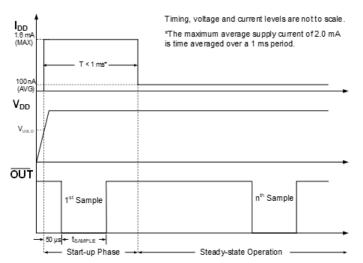


Figure 45: CT813x Power-On Timing Diagram

Omnipolar Magnetic Flux

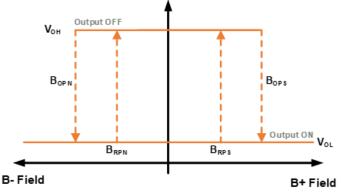


Figure 46: CT813x Response Time Curve

Table 1: CT8131 Open Drain Output Behavior

Magnetic Field	Condition	Output
Positive Field	B > B _{OPS}	Low (ON)
	0 < B < B _{RPS}	High-Z (OFF)
Negative Field	B < B _{OPN}	Low (ON)
Negative Field	0 > B > B _{RPN}	High-Z (OFF)

Table 2: CT8132 Push-Pull Output Behavior

Magnetic Field	Condition	Output
Positive Field	B > B _{OPS}	Low (ON)
	0 < B < B _{RPS}	High (OFF)
Negative Field	B < B _{OPN}	Low (ON)
	0 > B > B _{RPN}	High (OFF)



APPLICATIONS INFORMATION

A decoupling capacitor, C_{BYP} , between the supply voltage (VDD) and ground (GND) is required to lower the noise going into the CT8131 as well as providing isolation from the other circuits. The decoupling capacitor should be placed close to the TMR digital latch. A typical capacitor value of 1.0 μ F (ceramic) will be sufficient. A pull-up resistor of 47 k Ω connected from OUT to the system voltage (V_{SYS}) is required for the CT8131.

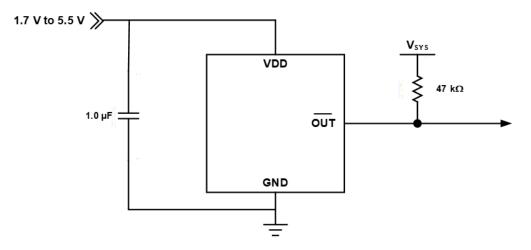


Figure 47: CT8131 Application Block Diagram

Like the CT8131, the CT8132 products require a 1.0 μ F (ceramic) bypass capacitor to be connected between the supply voltage and ground.

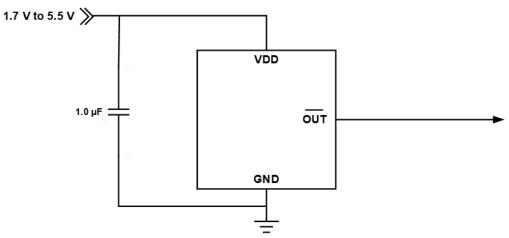


Figure 48: CT8132 Application Block Diagram



XtremeSense TMR Current Sensor Location

The XtremeSense TMR sensor location for the CT813x products are shown in Figure 49 and Figure 50. The dimensions shown in both figures are typical values.

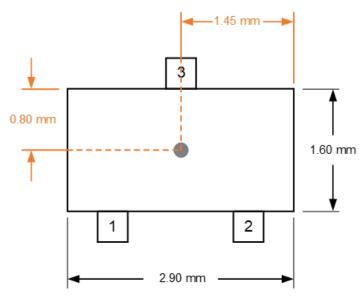


Figure 49: XtremeSense TMR Sensor Location for CT813x products in 3-lead SOT23 Package

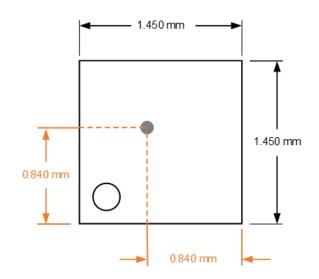


Figure 50: XtremeSense TMR Sensor Location for CT813x products in 4-lead LGA Package



PACKAGE OUTLINE DRAWINGS

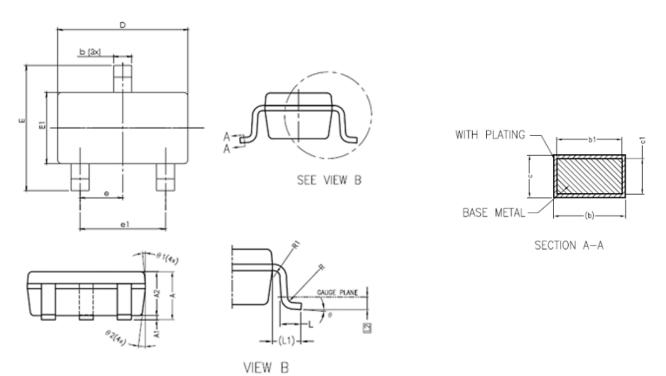


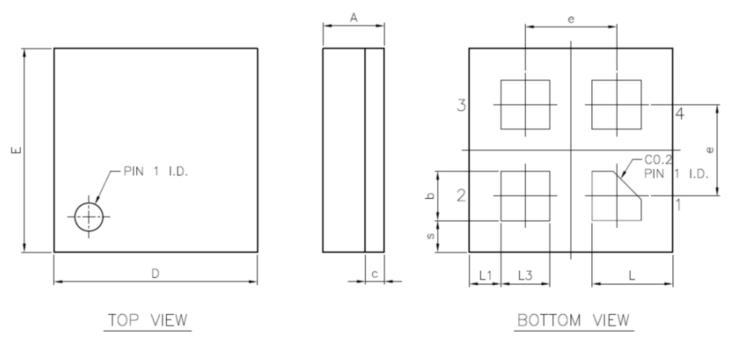
Figure 51: 3-Lead SOT23 Package Drawing

Table 3: CT813x 3-Lead SOT23 Package Dimensions

Currente e l	Dimens	sions in Millimeter	Cumhal		
Symbol	Min.	Тур.	Max.	Symbol	Ν
А	1.05	1.20	1.35	е	
A1	0.00	0.10	0.15	e1	
A2	1.00	1.10	1.20	L	C
b	0.30	_	0.50	L1	
b1	0.30	0.35	0.45	L2	
С	0.08	_	0.22	R	C
c1	0.08	0.13	0.20	R1	C
D	2.80	2.90	3.00	θ	
E	2.60	2.80	3.00	θ1	
E1	1.50	1.60	1.70	θ2	

Symbol	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
е		0.95 BSC				
e1		1.90 BSC				
L	0.35 0.43 0.60					
L1	0.50 REF					
L2	0.25 BSC					
R	0.10 – –					
R1	0.10	_	0.25			
θ	0° 4° 8°		8°			
θ1	5° 6° 15°		15°			
θ2	5° 8° 15°					





NOTES:

- 1. All dimensions are in millimeters.
- 2. Pin A1 ID is marked by ink or laser.

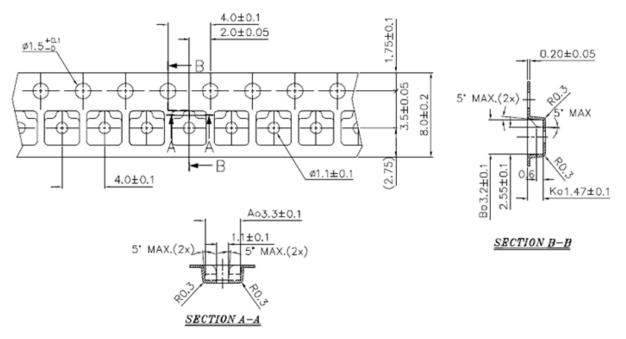
Figure	52:	4-Lead	LGA	Package	Drawing
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Cumula al	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
А	0.386	0.436	0.486			
b	0.300	0.350	0.400			
С	_	0.136 REF	_			
D	1.400	1.450	1.500			
E	1.400	1.450	1.500			
е	_	0.650	_			
L	0.525	0.575	0.625			
L1	0.175	0.225	0.275			
L3	0.300	0.350	0.400			
S	0.175	0.225	0.275			

Table 4: CT813x 4-Lead LGA Package Dimensions



TAPE AND REEL POCKET DRAWINGS AND DIMENSIONS



NOTES:

- 1. Material: Conductive Polystyrene.
- 2. Dimensions in mm.
- 3. 10 sprocket hole pitch cumulative tolerance ± 0.20 mm.
- 4. Camber not to exceed 1 mm in 100 mm.
- 5. Pocket position relative to sprocket hole measured as true position of pocket and not pocket hole.
- 6. (S.R. Ω /sq) means surface electric resistivity of the carrier tape.

Figure 53: Tape and Pocket Drawing for 3-lead SOT23 Package

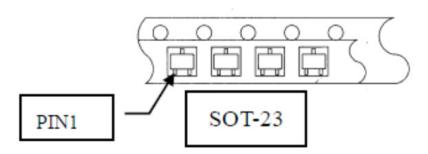


Figure 54: SOT23 Orientation in Tape Pocket



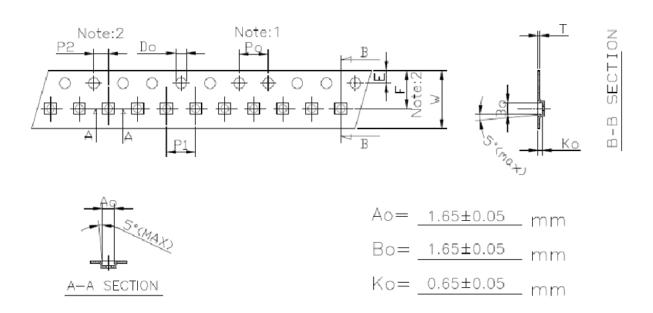


Figure 55: Tape and Pocket Drawing for LGA-4 Package

Symbol	Specification
Po	4.00 mm ± 0.10 mm
P1	4.00 mm ± 0.10 mm
P2	2.00 mm ± 0.05 mm
Do	1.50 mm ± 0.10 mm
D1	1.10 mm ± 0.05 mm
E	1.75 mm ± 0.10 mm
F	3.50 mm ± 0.05 mm
10Po	40.00 mm ± 0.10 mm
W	8.00 mm ± 0.20 mm
Т	0.25 mm ± 0.02 mm

Table 5: LGA-4 Tape and Pocket Dimensions

NOTES:

- 1. 10 sprocket hole pitch cumulative tolerance is ± 0.10 mm.
- 2. Pocket position is relative to sprocket hole measured as true position of pocket and not pocket hole.
- 3. Ao and Bo measured on a place of 0.3 mm above the bottom of the pocket to top surface of the carrier.
- 4. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 5. Carrier camber shall not more than 1 mm per 100 mm through a length of 250 mm.



Integrated Omnipolar TMR Digital Latches

PACKAGE INFORMATION

Table 6: CT813x Package Information

Part Number	Package Type	# of Leads	Package Quantity	Lead Finish	Eco Plan ^[1]	MSL Rating ^[2]	Operating Temperature (°C) ^[3]	Device Marking ^[4]
CT8131BV-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	LYZ
CT8131BV-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	LYZ
CT8131BV-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	JD YWWS
CT8131BV-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	JD YWWS
CT8132BH-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	G YZ
CT8132BH-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	G YZ
CT8132BH-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MG YWWS
CT8132BH-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MG YWWS
CT8132BL-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MB YWWS
CT8132BL-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MB YWWS
CT8132BV-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	MYZ
CT8132BV-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	M YZ
CT8132BV-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MAYWWS
CT8132BV-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MAYWWS
CT8132DM-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MD YWWS
CT8132DM-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MD YWWS
CT8132EK-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MF YWWS
CT8132EK-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MF YWWS
CT8132SK-IL4	LGA	4	3000	Au	Green & RoHS	3	-40 to 85	P YZ U YZ
CT8132SK-HL4	LGA	4	3000	Au	Green & RoHS	3	-40 to 125	V YZ X YZ
CT8132SK-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MC YWWS
CT8132SK-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MC YWWS
CT8132SL-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	ME YWWS
CT8132SL-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	ME YWWS

[1] RoHS is defined as semiconductor products that are compliant to the current EU RoHS requirements. It also will meet the requirement that RoHS substances do not exceed 0.1% by weight in homogeneous materials. Green is defined as the content of chlorine (CI), bromine (Br), and antimony trioxide based flame retardants satisfy JS709B low halogen requirements of ≤ 1,000 ppm.

^[2] MSL Rating = Moisture Sensitivity Level Rating as defined by JEDEC standard classifications.

^[3] Package will withstand ambient temperature range of -40°C to 150°C and storage temperature range of -65°C to 150°C.

^[4] Device Marking for SOT23 is defined as XZ YWWS where XZ = part number nominator, Y = year, WW = work week, and S = sequential number. LGA is defined as X where X = part number nominator and YZ = date code information.



Revision History

Number	Date	Description			
1	December 11, 2023	Document rebranded and minor editorial updates			
2	February 29, 2024	Updated Selection Guide (page 2)			
3	March 22, 2024	Updated Operate Point and Hysteresis values for CT8132SK (page 18)			

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